Vishay Semiconductors

AAP Gen 7 (TO-240AA) Power Modules Standard Diodes, 80 A



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AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	80 A				
Type	Modules - Diode, High Voltage				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration	Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode				

MECHANICAL DESCRIPTION

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- · High voltage
- Industrial standard package



- · Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
1		80	A			
I _{F(AV)}	T _C	110	°C			
I _{F(RMS)}		126				
I _{FSM}	50 Hz	1500	Α			
	60 Hz	1570				
l ² t	50 Hz	11.25	kA ² s			
	60 Hz	10.26	KA-S			
l ² √t		112.5	kA²√s			
V _{RRM}	Range	400 to 1600	V			
T _{Stg} , T _J		-40 to +150	°C			

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	08	800	900				
VS-VSK.71	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	180° conduction, half sine wave			A °C	
Maximum RMS forward current	I _{F(RMS)}				126		
		t = 10 ms	No voltage		1500		
Maximum peak, one-cycle forward,	I	t = 8.3 ms	reapplied		1570	Α	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1260		
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1320		
	l ² t	t = 10 ms	No voltage	initial T _J = T _J maximum	11.25	kA ² s	
Maximum I ² t for fusing		t = 8.3 ms	reapplied		10.26		
I Waxiindiii i-t ioi idsiiig		t = 10 ms	100 % V _{RRM}		7.95		
		t = 8.3 ms	reapplied		7.23		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	112.5	kA ^{2√} s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	$I_{F(AV)}$, $T_J = T_J$ maximum	0.73	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.83	V	
Low level value of forward slope resistance	r _{f1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		3.22	mΩ		
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		2.89	11152		
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25$ °C, $t_p = 400 \mu s$ square wave		1.6	V		

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA		
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V		



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS		
Junction and storage temp	erature range	T _J , T _{Stg}		-40 to +150	°C		
Maximum internal thermal resistance, junction to case per leg		R _{thJC}	DC operation 0.28		2014		
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1	°C/W		
	to heatsink		A mounting compound is recommended and the	4			
Mounting torque ± 10 %	busbar		torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm		
Approximate weight				75	g		
				2.7	OZ.		
Case style			JEDEC®	AAP Gen 7	(TO-240AA)		

△R CONDUCTION PER JUNCTION											
DEVICES	8	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				LINUTO
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.075	0.088	0.113	0.155	0.228	0.06	0.094	0.12	0.158	0.23	°C/W

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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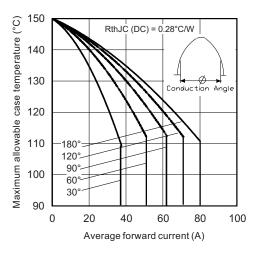


Fig. 1 - Current Ratings Characteristics

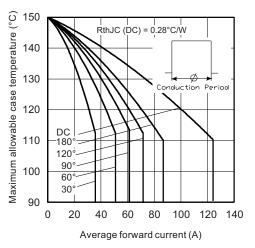


Fig. 2 - Current Ratings Characteristics

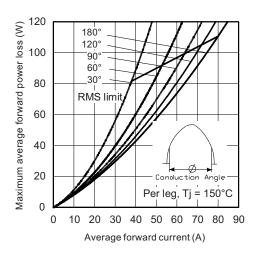


Fig. 3 - Forward Power Loss Characteristics

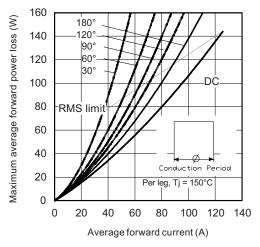
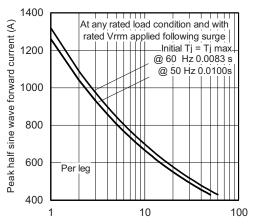


Fig. 4 - Foward Power Loss Characteristics



Number of equal amplitude half cycle current pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

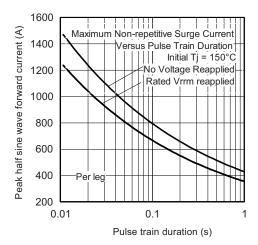


Fig. 6 - Maximum Non-Repetitive Surge Current

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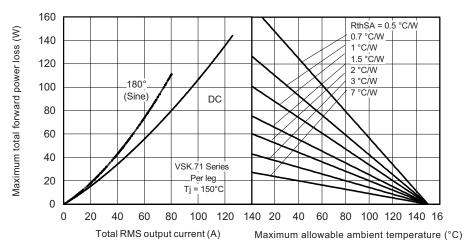


Fig. 7 - Forward Power Loss Characteristics

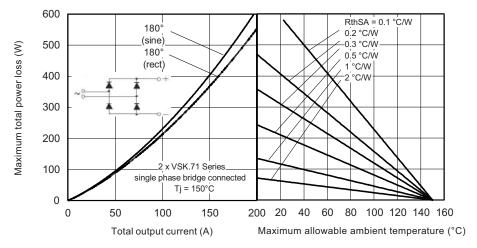


Fig. 8 - Forward Power Loss Characteristics

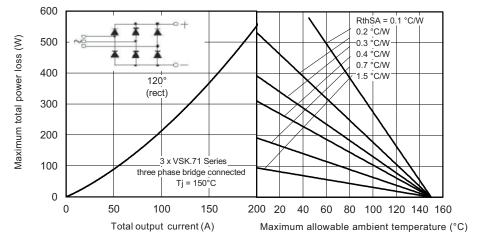


Fig. 9 - Forward Power Loss Characteristics

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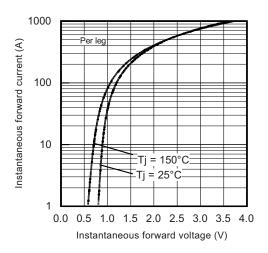


Fig. 10 - Forward Voltage Characteristics

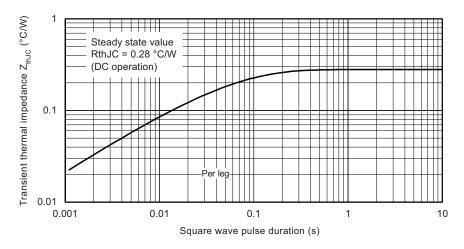
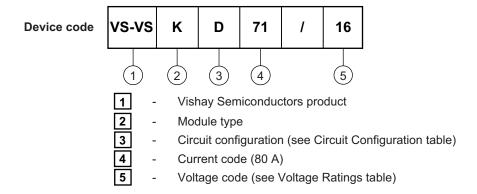


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



Note

• To order the optional hardware go to www.vishay.com/doc?95172

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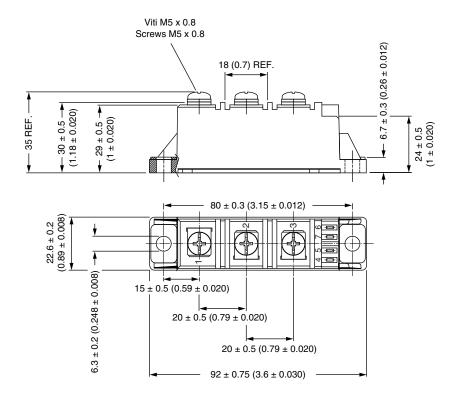
CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Two diodes doubler circuit	D	VSKD (1) 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
Two diodes common cathode	С	VSKC (1) - (2) - (3)
Two diodes common anode	J	VSKJ (1) 0
Single diode	E	VSKE (1) 0

LINKS TO RELAT	
Dimensions	www.vishay.com/doc?95369

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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